

# Numerical Simulation of Heat Transfer in Materials with Anisotropic Thermal Conductivity: A Finite Volume Scheme to Handle Complex Geometries

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IMA Workshop:  
New Paradigms in Computation  
Minneapolis, March 28–30, 2005

## Complex Sample Domain from Crystal Growth

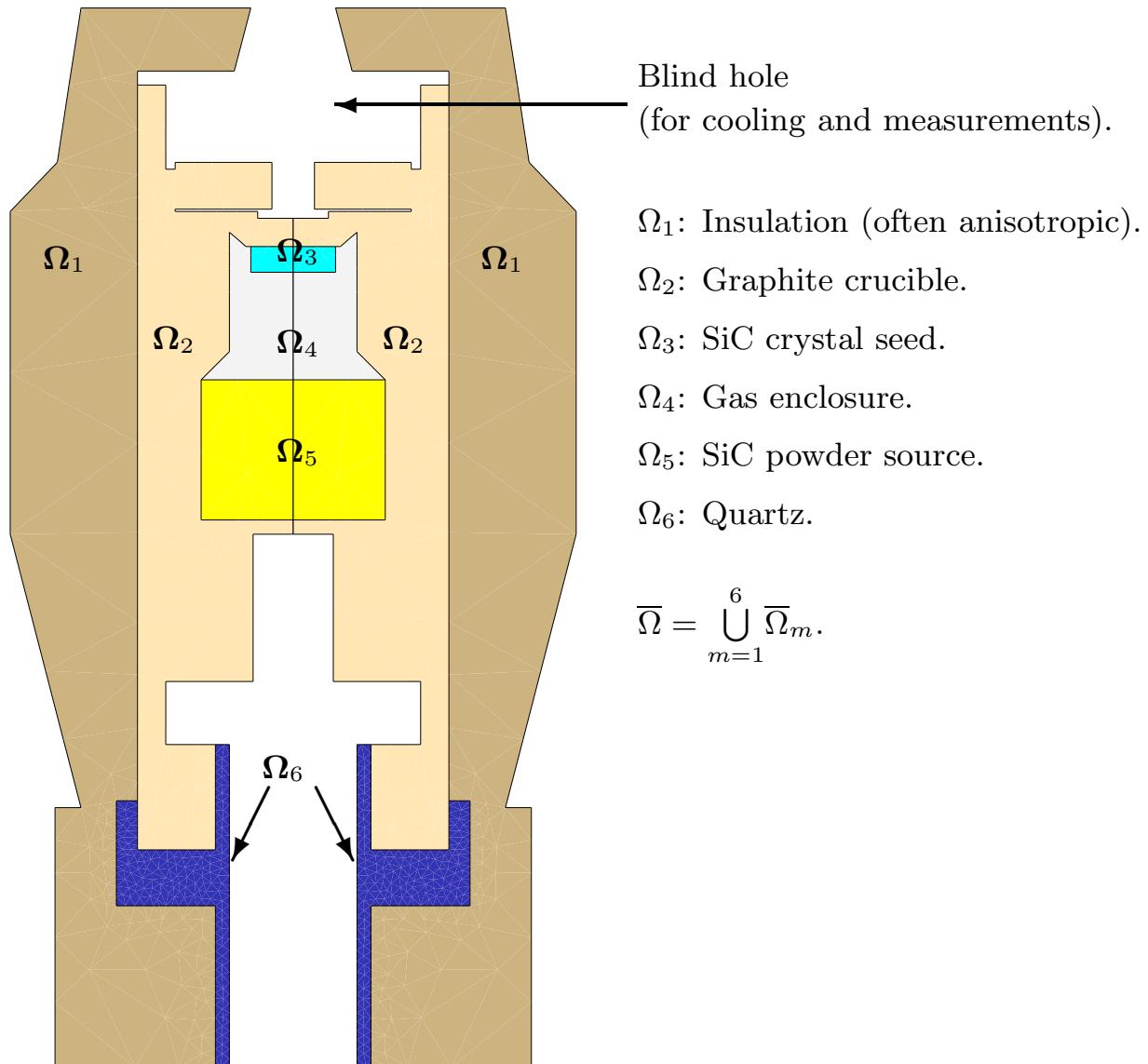


Figure 1: Axisymmetric domain representing a growth apparatus used in silicon carbide single crystal growth by physical vapor transport (PVT). The geometry is a modified version of K. Semmelroth et al., J. Phys.-Condes. Matter 16 (2004).

## Model for Stationary Anisotropic Heat Conduction

$$-\operatorname{div}(K_m(\theta) \nabla \theta) = f_m \quad \text{in } \Omega_m \quad (m \in M),$$

$\theta$ : absolute temperature,  $K_m$ : symmetric and positive definite tensor of thermal conductivity,  $f_m$ : heat sources,  $\Omega_m$ : domain of material  $m$ .

Assumed form of  $K_m$ :

$$K_m(\theta) = \kappa_{i,j}^m(\theta) , \quad \text{where} \quad \kappa_{i,j}^m(\theta) = \begin{cases} \alpha_i^m \kappa_{\text{iso}}^m(\theta) & \text{for } i = j, \\ 0 & \text{for } i \neq j. \end{cases}$$

Interface Conditions on  $\overline{\Omega}_{m_1} \cap \overline{\Omega}_{m_2}$ :

$$K_{m_1}(\theta) \nabla \theta \mid_{\overline{\Omega}_{m_1}} \bullet \mathbf{n}_{m_1} = K_{m_2}(\theta) \nabla \theta \mid_{\overline{\Omega}_{m_2}} \bullet \mathbf{n}_{m_1}.$$

$\mid$ : restriction,  $\mathbf{n}_{m_1}$ : outer unit normal vector to material  $m_1$ .

Boundary Conditions: Dirichlet, Robin

$$\theta = \theta_{\text{Dir}} \quad \text{on } \overline{\Gamma}_{\text{Dir}},$$

$$- K_m(\theta) \nabla \theta \bullet \mathbf{n}_m = \xi_m (\theta - \theta_{\text{ext}}) \quad \text{on } \Gamma_{\text{Rob}} \cap \partial \Omega_m, m \in M,$$

## Finite Volume Discretization

$\Sigma_m = (\sigma_{m,i})_{i \in I_m}$  conforming triangulation of  $\Omega_m$  satisfying the **constrained Delaunay property**: If  $\gamma$  is an interior edge of  $\Sigma_m$ ,  $\alpha$  and  $\beta$  the angles opposite to  $\gamma$ , then  $\alpha + \beta \leq \pi$ . If  $\gamma \subseteq \partial\Omega_m$  is a boundary edge of  $\Sigma_m$ ,  $\alpha$  the angle opposite  $\gamma$ , then  $\alpha \leq \pi/2$ .

$V(\sigma_{m,i}) = v_{i,j}^m : j \in \{1, 2, 3\}$  : Set of vertices.

$V := \bigcup_{m \in M, i \in I_m} V(\sigma_{m,i})$ .

$$\begin{aligned}\omega_v &:= x \in \Omega : \|x - v\|_2 < \|x - z\|_2 \text{ for each } z \in V \setminus \{v\} , \\ \omega_{m,v} &:= \omega_v \cap \Omega_m, \quad V_m := \{z \in V : \omega_{m,z} \neq \emptyset\}.\end{aligned}$$

$$A_m = (a_{i,j}^m), \quad a_{i,j}^m := \begin{cases} \alpha_i^m & \text{for } i = j, \\ 0 & \text{for } i \neq j. \end{cases}$$

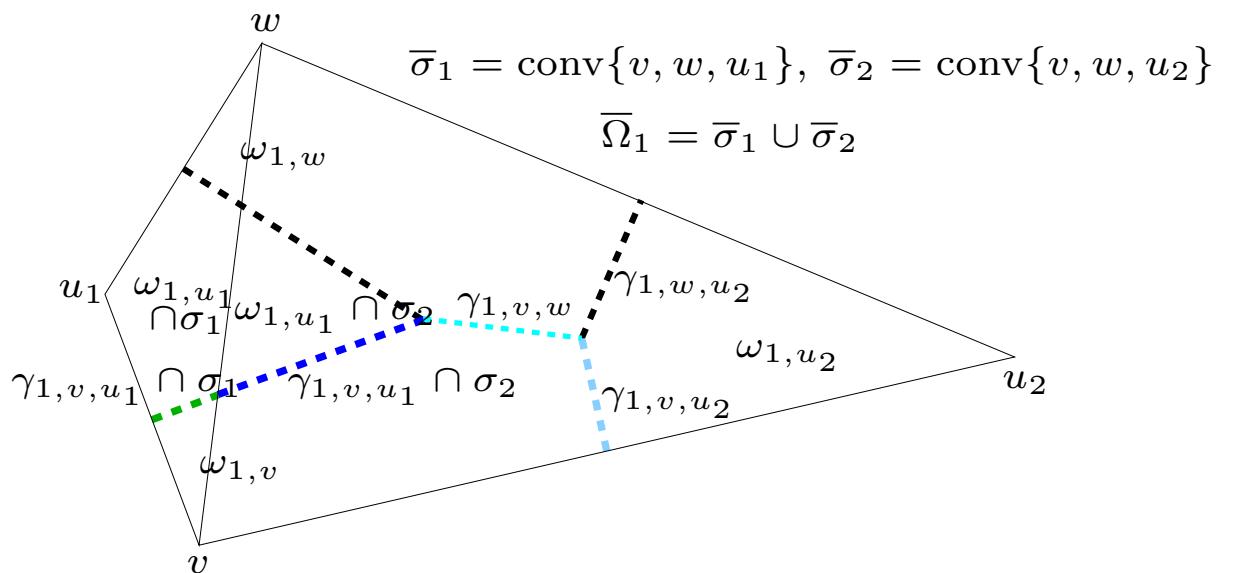


Figure 2: Illustration of the space discretization.

## Approximation of Anisotropic Terms

$\phi_{\sigma,v} : \sigma \longrightarrow [0, 1]$ : Affine coordinates on triangle  $\sigma$  w.r.t.  $v \in V(\sigma)$ .  
 For each edge  $[v, w]$  of some  $\sigma \in \Sigma_m$ :

$$\Sigma_{m,v,w} := \sigma \in \Sigma_m : \{v, w\} \subseteq V(\sigma) .$$

Letting

$$\Sigma_{\gamma_{m,v,w}} := \sigma \in \Sigma_{m,v,w} : \lambda_1(H_{v,w,\sigma} \cap \gamma_{m,v,w}) \neq 0 ,$$

decompose  $\gamma_{m,v,w}$ :

$$\gamma_{m,v,w} = \bigcup_{\sigma \in \Sigma_{\gamma_{m,v,w}}} \bar{\sigma} \cap \gamma_{m,v,w}.$$

Approximation:

$$(A_m \nabla \theta)|_\sigma \bullet \mathbf{n}_{\omega_v}|_{\gamma_{m,v,w}} \approx \sum_{\tilde{v} \in V(\sigma)} \theta(\tilde{v}) (A_m \nabla \phi_{\sigma,\tilde{v}}) \bullet \frac{w - v}{\|w - v\|_2}.$$

## Finite Volume Scheme

Find  $(\theta_v)_{v \in V}$  satisfying:

$$\theta_v = \theta_{\text{Dir}}(v) \quad \text{for each } v \in V_{\text{Dir}},$$

$$\begin{aligned} 0 &= \sum_{m \in M} \xi_m \theta_v - \theta_{\text{ext}}(v) \lambda_1(\partial \omega_{m,v} \cap \Gamma_{\text{Rob}}) \\ &\quad - \sum_{m \in M} \sum_{\sigma \in \Sigma_{\gamma_{m,v,w}}} \frac{1}{2} \kappa_{\text{iso}}^m(\theta_v) + \kappa_{\text{iso}}^m(\theta_w) \\ &\quad \sum_{\tilde{v} \in V(\sigma)} \theta_{\tilde{v}} (A_m \nabla \phi_{\sigma,\tilde{v}}) \bullet \frac{w - v}{\|w - v\|_2} \lambda_1(H_{v,w,\sigma} \cap \gamma_{m,v,w}) \\ &\quad - \sum_{m \in M} f_{m,v} \lambda_2(\omega_{m,v}) \quad \text{for each } v \in V_{\neg \text{Dir}} = V \setminus V_{\text{Dir}}. \end{aligned}$$

## Comparison with Closed-Form Solution

### Axisymmetric Single-Material Domain

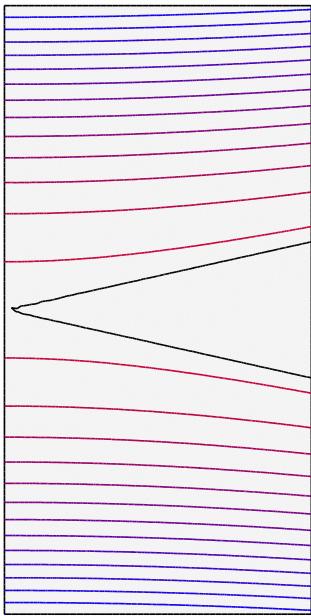
$$\Omega = \{(r, z) : 0 < r < 0.2, -0.2 < z < 0.2\}:$$

$$-\frac{1}{r} \frac{\partial}{\partial r} \left[ r \alpha_r \frac{\partial \theta}{\partial r} \right] - \frac{\partial}{\partial z} \left[ \alpha_z \frac{\partial \theta}{\partial z} \right] = 0 \quad \text{in } \Omega, \quad (1a)$$

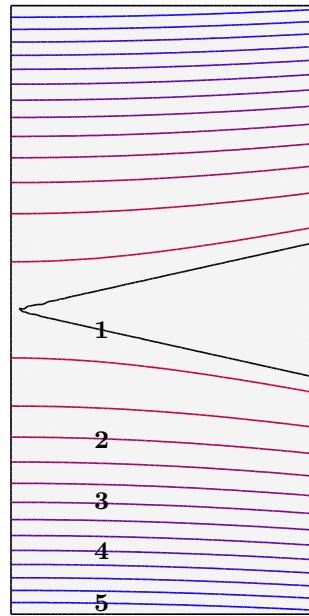
$$\theta_{\text{Dir}}(r, z) := \frac{1}{2} \frac{1}{\alpha_r} r^2 - \frac{1}{\alpha_z} z^2 \quad \text{on } \partial\Omega. \quad (1b)$$

$$\text{Solution: } \theta(r, z) = \frac{1}{2} \frac{1}{\alpha_r} r^2 - \frac{1}{\alpha_z} z^2 \quad \text{on } \overline{\Omega}.$$

Numerical solution  $\theta_{\text{num}}^0$



Exact solution  $\theta$



Levels:  
 1: 0.0  
 2: -0.009  
 3: -0.018  
 4: -0.027  
 5: -0.036

Figure 3: Solution of (1): Numerical  $\theta_{\text{num}}^0$ , 3117 triangles (left); exact  $\theta$  (right). Isolevel difference: 0.003.

$$\text{Discrete } L_1\text{-error: } \epsilon_{L_1}^l := \sum_{v \in V^l} \text{vol}(\omega_v) |\theta_{\text{num}}^l(v) - \theta(v)|,$$

$v \in V^l$ : vertices,  $\text{vol}(\omega_v)$ :  $r$ -weighted area of Voronoï cell.

Numerical convergence rate:

$$\rho_{L_1}^l := (\ln(\epsilon_{L_1}^l) - \ln(\epsilon_{L_1}^{l-1})) / (\ln(h^l) - \ln(h^{l-1})),$$

$h^l$ : upper bound for triangle area of level  $l$ .

## Axisymmetric Multi-Material Domain

$$\Omega_1 = \{(r, z) : 0 < r < r_0, 0 < z < z_0\},$$

$$\Omega_2 = \{(r, z) : r_0 < r < r_{\max}, 0 < z < z_0\},$$

$$\Omega_3 = \{(r, z) : 0 < r < r_0, z_0 < z < z_{\max}\},$$

$$\Omega_4 = \{(r, z) : r_0 < r < r_{\max}, z_0 < z < z_{\max}\},$$

$$-\frac{1}{r} \frac{\partial}{\partial r} \left[ r \alpha_{m,r} \frac{\partial \theta}{\partial r} \right] - \frac{\partial}{\partial z} \left[ \alpha_{m,z} \frac{\partial \theta}{\partial z} \right] = f_m \quad \text{in } \Omega_m, \quad (2a)$$

$$\left( \begin{pmatrix} \alpha_{m,r} & 0 \\ 0 & \alpha_{m,z} \end{pmatrix} \nabla \theta|_{\bar{\Omega}_m} \right) \bullet \mathbf{n}_m \quad (2b)$$

$$= \left( \begin{pmatrix} \alpha_{\tilde{m},r} & 0 \\ 0 & \alpha_{\tilde{m},z} \end{pmatrix} \nabla \theta|_{\bar{\Omega}_{\tilde{m}}} \right) \bullet \mathbf{n}_m \quad \text{on } \partial\Omega_m \cap \partial\Omega_{\tilde{m}},$$

$$\theta_{\text{Dir},m}(r, z) := a_m r^2 + b_m z^2 + c_m \quad \text{on } \partial\Omega \cap \partial\Omega_m. \quad (2c)$$

Solution:

$$\theta(r, z) := a_m r^2 + b_m z^2 + c_m \quad \text{on } \bar{\Omega}_m,$$

$$\theta_{\text{Dir},m}(r, z) := a_m r^2 + b_m z^2 + c_m \quad \text{on } \partial\Omega \cap \partial\Omega_m,$$

where  $r_0 = z_0 = 0.1$ ,  $r_{\max} = z_{\max} = 0.2$ ,

$$\alpha_{1,r} = 2, \quad \alpha_{2,r} = 1, \quad \alpha_{3,r} = 4, \quad \alpha_{4,r} = 2,$$

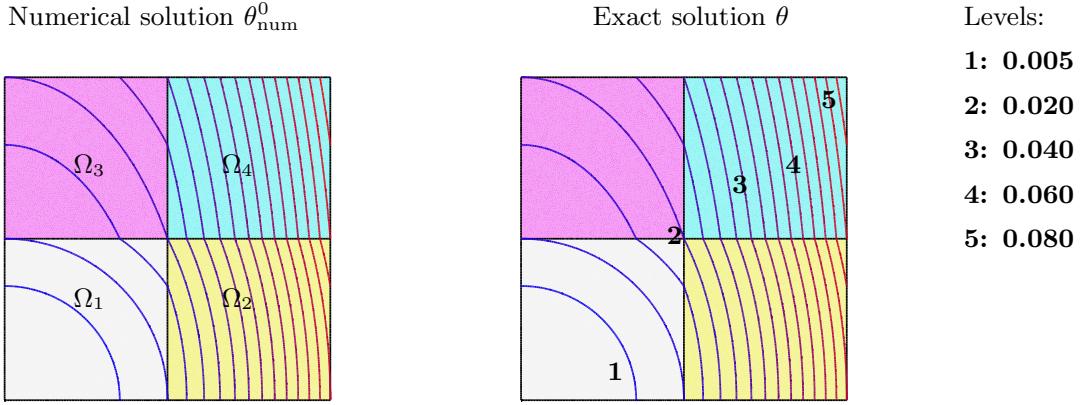
$$\alpha_{1,z} = 1, \quad \alpha_{2,z} = 2, \quad \alpha_{3,z} = 3, \quad \alpha_{4,z} = 6,$$

$$a_1 = 1, \quad a_2 = 2, \quad a_3 = 1, \quad a_4 = 2,$$

$$b_1 = 1, \quad b_2 = 1, \quad b_3 = 1/3, \quad b_4 = 1/3,$$

$$c_1 = 0, \quad c_2 = -1/100, \quad c_3 = 2/300, \quad c_4 = 1/300,$$

$$f_1 = -10, \quad f_2 = -12.0, \quad f_3 = -18.0, \quad f_4 = -20.0$$



**Figure 4:** Solution of (2): Numerical  $\theta_{\text{num}}^0$ , 3117 triangles (left); exact  $\theta$  (right). Isolevel difference: 0.005.

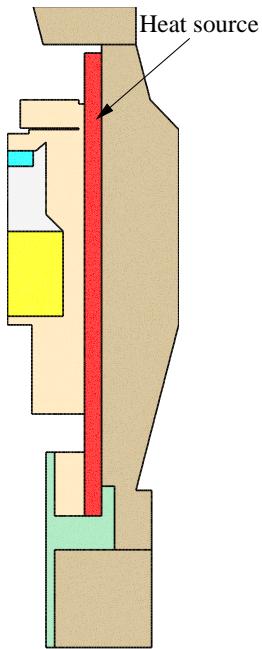
level $l$	number of triangles	max area $h^l$	$L_1$ -error $\epsilon_{L_1}^l$	numerical convergence rate $\rho_{L_1}^l$
0	3117	$4.0 \cdot 10^{-5}$	$5.013 \cdot 10^{-8}$	
1	12446	$1.0 \cdot 10^{-5}$	$1.260 \cdot 10^{-8}$	0.996125
2	49669	$2.5 \cdot 10^{-6}$	$3.244 \cdot 10^{-9}$	0.978789
3	198212	$6.25 \cdot 10^{-7}$	$8.2815 \cdot 10^{-10}$	0.984905
4	795195	$1.5625 \cdot 10^{-7}$	$2.0891 \cdot 10^{-10}$	0.993505

**Table 1:**  $L_1$ -error and numerical convergence rate for the numerical solution of (1) with anisotropy  $(\alpha_r, \alpha_z) = (10, 1)$ .

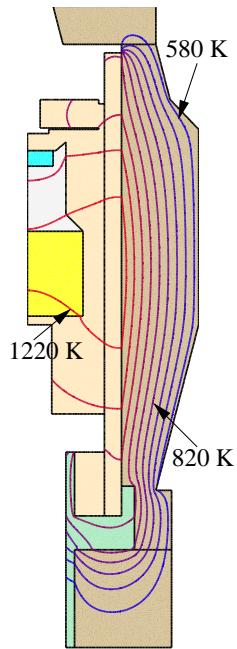
level $l$	number of triangles	max area $h^l$	$L_1$ -error $\epsilon_{L_1}^l$	numerical convergence rate $\rho_{L_1}^l$
0	1557	$4.0 \cdot 10^{-5}$	$2.1325 \cdot 10^{-6}$	
1	6148	$1.0 \cdot 10^{-5}$	$1.0669 \cdot 10^{-6}$	0.49956
2	24813	$2.5 \cdot 10^{-6}$	$5.259 \cdot 10^{-7}$	0.510282
3	99428	$6.25 \cdot 10^{-7}$	$2.638 \cdot 10^{-7}$	0.497672
4	398130	$1.5625 \cdot 10^{-7}$	$1.3362 \cdot 10^{-7}$	0.490654

**Table 2:**  $L_1$ -error and numerical convergence rate for the numerical solution of (2).

Stationary heat field



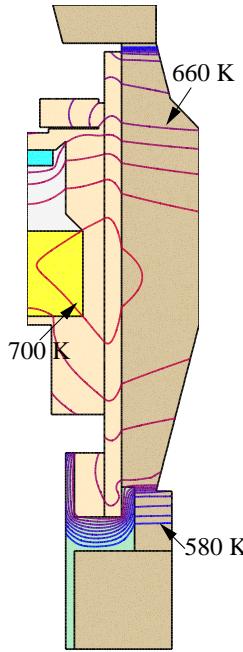
Stationary temperature field



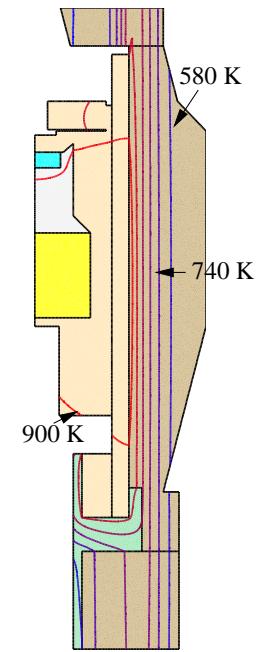
$\alpha_r$	$\alpha_z$	Maximal Temperature [K]
1	1	1273.18
1	10	1232.15
10	10	1238.38
10	1	918.35
1	1000	1063.58
1000	1000	1030.45
1000	1	706.36

Figure 5: Left: Domain of heat sources highlighted. Right:  $T$ -field for isotropic insulation, i.e.  $\alpha_r = \alpha_z = 1$ .

Stationary temperature field



Stationary temperature field



Stationary temperature field

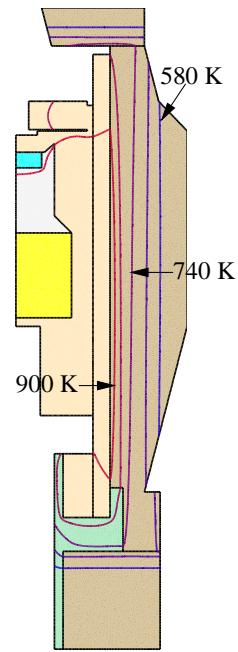


Figure 6:  $T$ -field for anisotropic insulation with  $\alpha_r = 1000$  (left), with  $\alpha_r = 1000$  for sides,  $\alpha_z = 1000$  for top and bottom (middle),  $\alpha_z = 1000$  (right).

## Publications

- P. PHILIP: *Transient Numerical Simulation of Sublimation Growth of SiC Bulk Single Crystals. Modeling, Finite Volume Method, Results*, Thesis, Department of Mathematics, Humboldt University of Berlin, Germany, 2003 Report No. 22, Weierstrass Institute for Applied Analysis and Stochastics, Berlin.
- J. GEISER, O. KLEIN, P. PHILIP: *Numerical simulation of heat transfer in materials with anisotropic thermal conductivity: A finite volume scheme to handle complex geometries*. In preparation.
- J. GEISER, O. KLEIN, P. PHILIP: *Influence of anisotropic thermal conductivity in the apparatus insulation for sublimation growth of SiC: Numerical investigation of heat transfer*. In preparation.

## Funding:

Supported by the DFG Research Center “Matheon: Mathematics for Key Technologies” in Berlin, by the IMA in Minneapolis, and by the WIAS in Berlin.